



# **HiPerFRED Module**

 $V_{RRM} = 600 V$ 

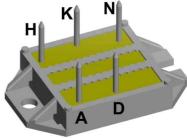
 $I_{DAV} = 86 A$ 

 $t_{rr} = 35 \, \text{ns}$ 

Fast Recovery Epitaxial Diode Low Loss and Soft Recovery 3~ Rectifier Bridge

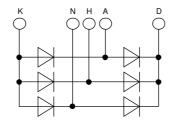
Part number

VUE75-06NO7



Backside: isolated





## Features / Advantages:

- Package with DCB ceramic base plate
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

## **Applications:**

- Supplies for DC power equipment
- Input and output rectifiers for high frequency
- Battery DC power supplies
- Field supply for DC motors

## Package: ECO-PAC1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
  Base plate: Di
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

#### **Disclaimer Notice**

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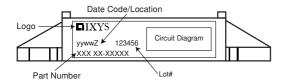


Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			600	V
$V_{RRM}$	max. repetitive reverse blocking ve	oltage	$T_{VJ} = 25^{\circ}C$			600	V
IR	reverse current, drain current	$V_R = 600 \text{ V}$	$T_{VJ} = 25^{\circ}C$			250	μΑ
		$V_R = 600 V$	$T_{VJ} = 150$ °C			1	mΑ
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 30 A	$T_{VJ} = 25^{\circ}C$			1.57	V
		$I_F = 90 A$				2.20	V
		$I_F = 30 \text{ A}$	T <sub>vJ</sub> = 150°C			1.22	V
		$I_F = 90 A$				1.75	V
I <sub>DAV</sub>	bridge output current	T <sub>C</sub> = 100°C	T <sub>vJ</sub> = 150°C			86	Α
		rectangular $d = \frac{1}{3}$					
V <sub>F0</sub>	threshold voltage	an adadation only	T <sub>vJ</sub> = 150°C			0.98	V
r <sub>F</sub>	slope resistance	ess calculation only				8	mΩ
R <sub>thJC</sub>	thermal resistance junction to case	9				0.9	K/W
R <sub>thCH</sub>	thermal resistance case to heatsin	nk			0.30		K/W
P <sub>tot</sub>	total power dissipation		$T_{C} = 25^{\circ}C$			140	W
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			250	Α
CJ	junction capacitance	$V_R = 400  \text{V}$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		26		pF
I <sub>RM</sub>	max. reverse recovery current	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	T <sub>vJ</sub> = 25 °C		6		Α
		$I_F = 30 \text{ A}; V_R = 300 \text{ V}$	$T_{VJ} = 100 ^{\circ}\text{C}$		10		Α
t <sub>rr</sub>	reverse recovery time	$\begin{cases} I_F = 30 \text{ A}; V_R = 300 \text{ V} \\ -\text{di}_F/\text{dt} = 200 \text{ A}/\mu\text{s} \end{cases}$	$T_{VJ} = 25 ^{\circ}\text{C}$		35		ns
		l	$T_{VJ} = 100^{\circ}\text{C}$		100		ns





Package ECO-PAC1			ı	Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal				100	Α
T <sub>VJ</sub>	virtual junction temperature			-40		150	°C
T <sub>op</sub>	operation temperature			-40		125	°C
T <sub>stg</sub>	storage temperature			-40		125	°C
Weight					19		g
M <sub>D</sub>	mounting torque			1.4		2	Nm
d <sub>Spp/App</sub>	creepage distance on surface   striking distance through air		terminal to terminal	6.0			mm
$d_{\text{Spb/Apb}}$			terminal to backside	10.0			mm
V <sub>ISOL</sub>	isolation voltage	t = 1 second	50/00 LL 51/0 L	3600			
.002		t = 1 minute	50/60 Hz, RMS; IsoL ≤ 1 mA	3000			٧

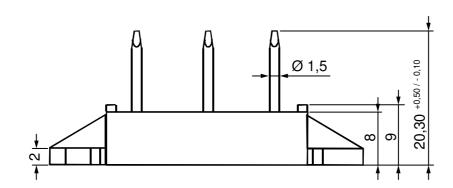


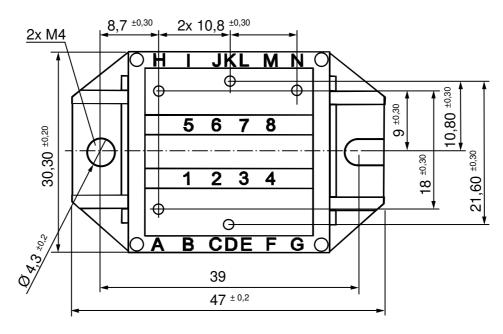
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUE75-06NO7	VUE75-06NO7	Box	25	482846

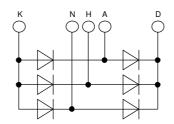
<b>Equivalent Circuits for Simulation</b>			* on die level	$T_{VJ} = 150$ °C
I - V <sub>0</sub>	)—[R <sub>0</sub> ]	Fast Diode		
V <sub>0 max</sub>	threshold voltage	0.98		V
$R_{0max}$	slope resistance *	6		$m\Omega$



# **Outlines ECO-PAC1**









#### **Fast Diode**

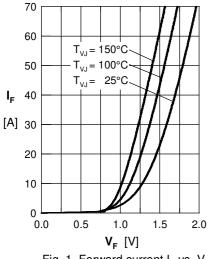


Fig. 1 Forward current I<sub>F</sub> vs. V<sub>F</sub>

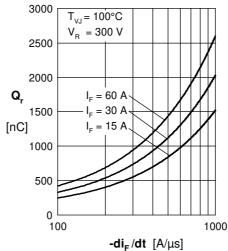


Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$ 

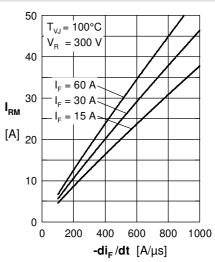


Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$ 

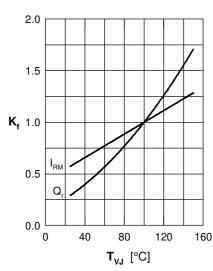


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$ 

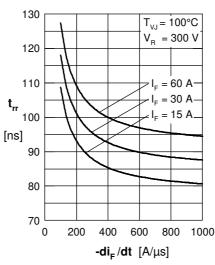


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_{F}/dt$ 

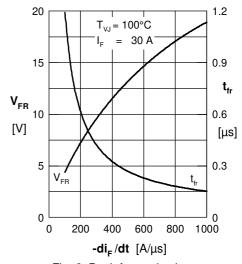


Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{fr}$  vs.  $-di_F/dt$ 

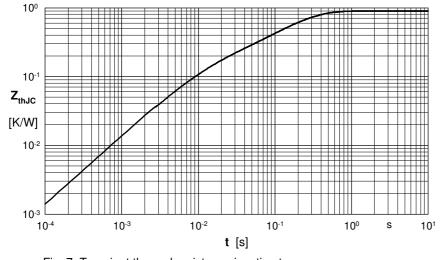


Fig. 7 Transient thermal resistance junction to case

Constants for  $\boldsymbol{Z}_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	t <sub>i</sub> (s)
1	0.3012	0.0052
2	0.1160	0.0003
3	0.0241	0.0004
4	0.4586	0.0092